

SEMITOP[®] 2

IGBT Module

SK20GD065

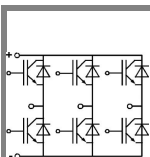
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- Ultrafast NPT technology IGBT
- CAL technology FWD
- High short circuit capability
- Low tail current with low temperature dependence

Typical Applications*

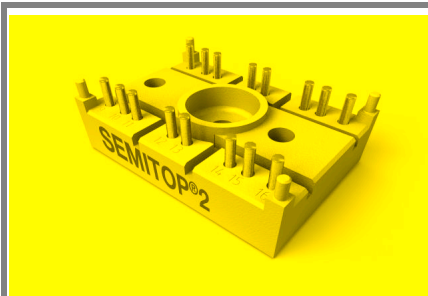
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS



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Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	$T_j = 25\text{ °C}$	600	V
I_C	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	24 A
		$T_s = 80\text{ °C}$	17 A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	40	A
V_{GES}		± 20	V
t_{psc}	$V_{CC} = 300\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125\text{ °C}$ $V_{CES} < 600\text{ V}$	10	μs
Inverse Diode			
I_F	$T_j = 125\text{ °C}$	$T_s = 25\text{ °C}$	22 A
		$T_s = 80\text{ °C}$	15 A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$	30	A
Module			
$I_{t(RMS)}$			A
T_{vj}		-40 ... +150	$^{\circ}\text{C}$
T_{stg}		-40 ... +125	$^{\circ}\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0,5\text{ mA}$	3	4	5	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$	$T_j = 25\text{ °C}$		0,07	mA
		$T_j = 125\text{ °C}$			mA
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V}$	$T_j = 25\text{ °C}$		120	nA
		$T_j = 125\text{ °C}$			nA
V_{CE0}		$T_j = 25\text{ °C}$	1,2	1,3	V
		$T_j = 125\text{ °C}$	1,1	0,9	V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}$	40		$\text{m}\Omega$
		$T_j = 125\text{ °C}$	55		$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 20\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25\text{ °C}_{chiplev.}$	2		V
		$T_j = 125\text{ °C}_{chiplev.}$	2,2		V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	1,1		nF
C_{oes}			0,11		nF
C_{res}			0,063		nF
$t_{d(on)}$	$R_{Gon} = 30\ \Omega$	$V_{CC} = 300\text{ V}$ $I_C = 20\text{ A}$	36		ns
t_r			30		ns
E_{on}			0,7		mJ
$t_{d(off)}$	$R_{Goff} = 30\ \Omega$	$T_j = 125\text{ °C}$ $V_{GE} = \pm 15\text{ V}$	250		ns
t_f			60		ns
E_{off}			0,4		mJ
$R_{th(j-s)}$	per IGBT			1,7	K/W



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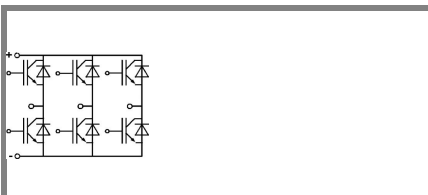
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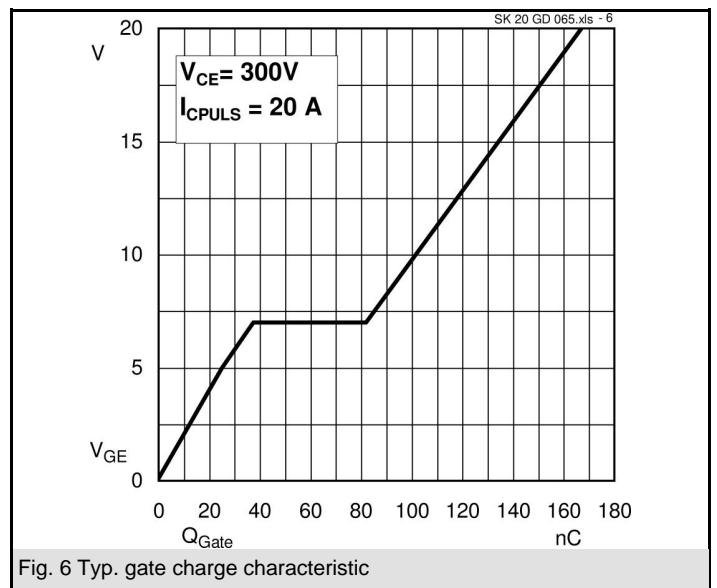
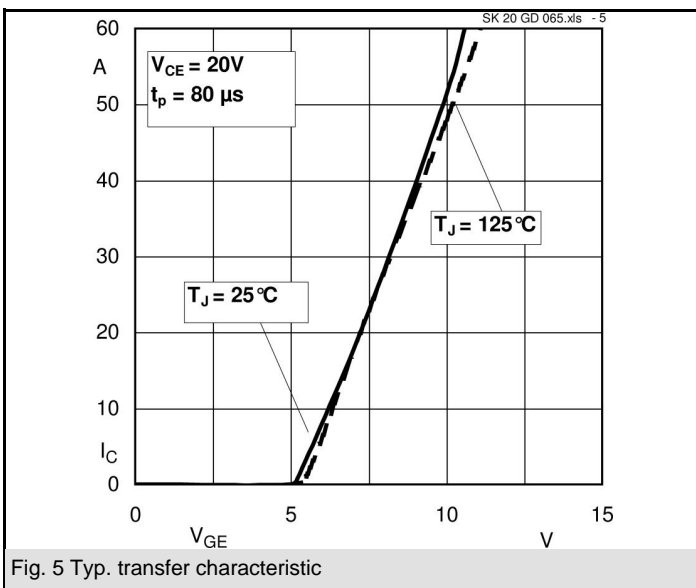
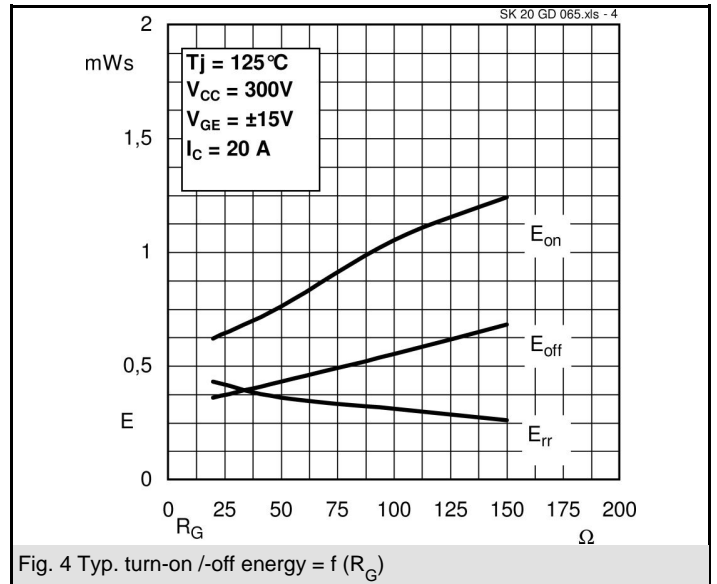
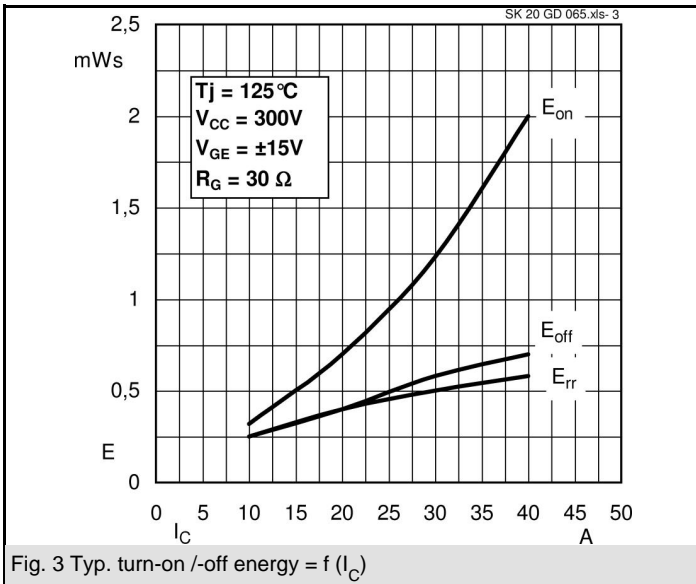
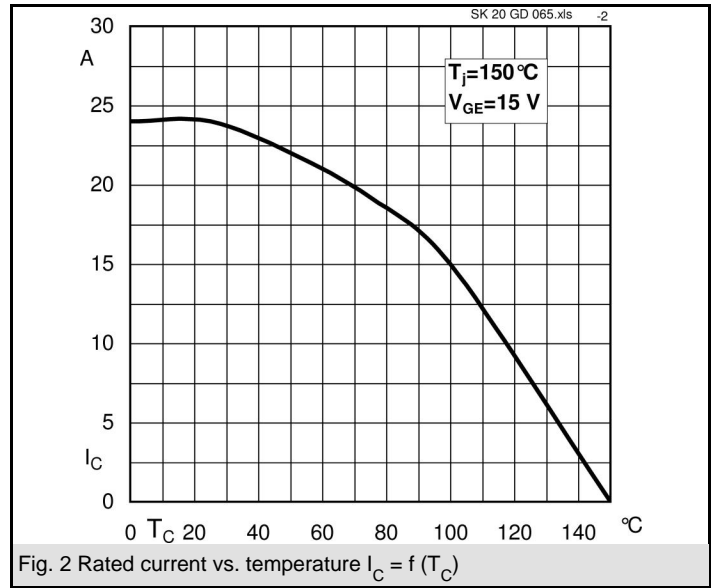
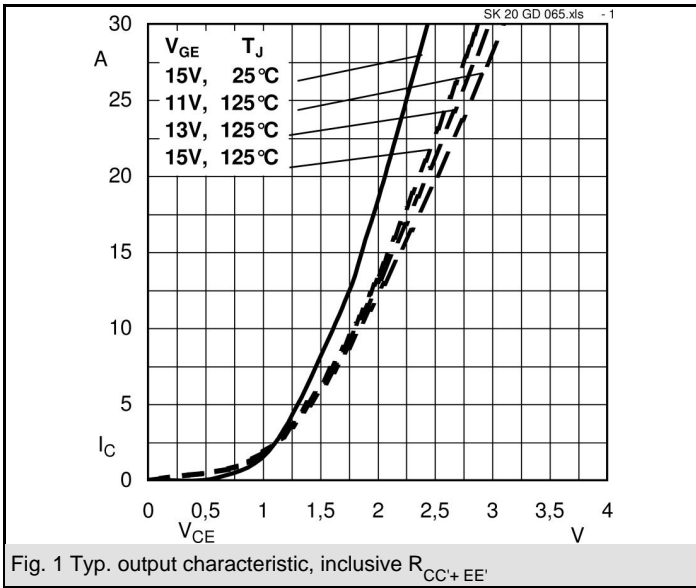
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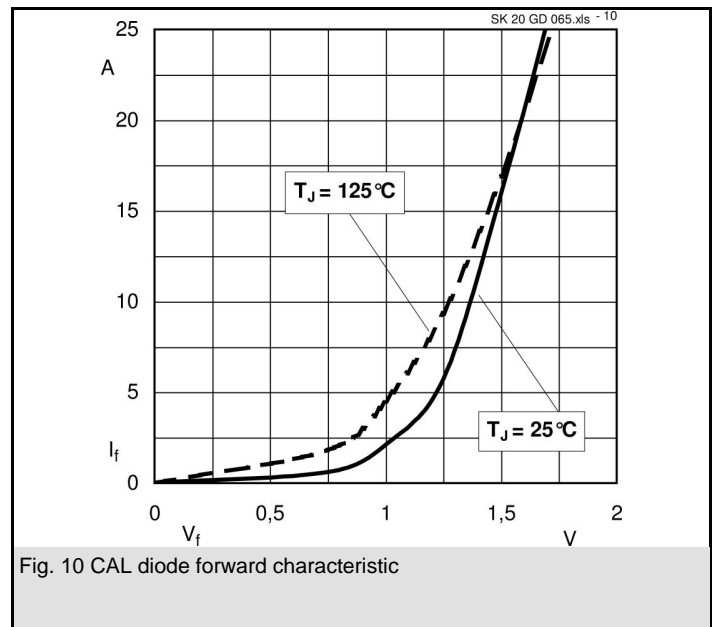
Characteristics

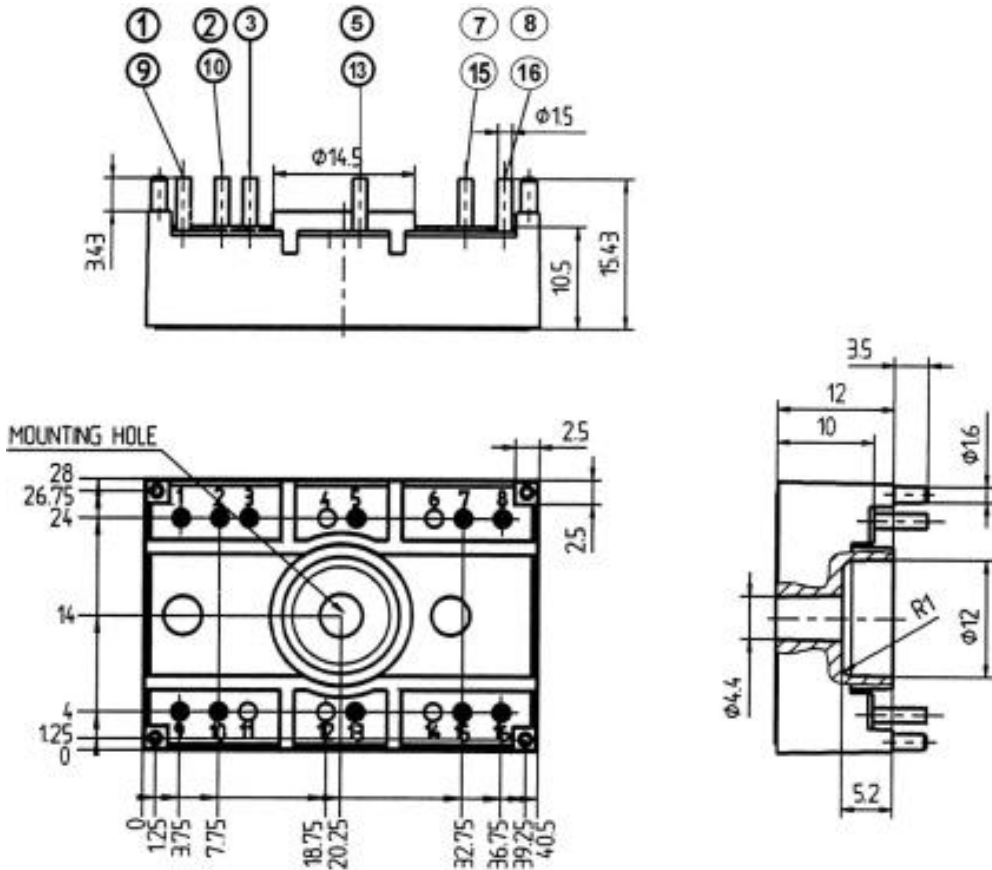
Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 20 \text{ A}; V_{GE} = 0 \text{ V}$				
	$T_j = 25 \text{ }^\circ\text{C}_{\text{chiplev.}}$		1,6	1,9	V
	$T_j = 125 \text{ }^\circ\text{C}_{\text{chiplev.}}$		1,9	1,9	V
V_{F0}					
	$T_j = 25 \text{ }^\circ\text{C}$		1	1,1	V
	$T_j = 125 \text{ }^\circ\text{C}$		0,9	1	V
r_F					
	$T_j = 25 \text{ }^\circ\text{C}$		30	40	mΩ
	$T_j = 125 \text{ }^\circ\text{C}$		33	47	mΩ
I_{RRM}	$I_F = 20 \text{ A}$		27		A
Q_{rr}	$di/dt = -1350 \text{ A}/\mu\text{s}$		2,3		μC
E_{rr}	$V_{CC} = 300\text{V}$		0,4		mJ
$R_{th(j-s)D}$	per diode			2,3	K/W
M_s	to heat sink			2	Nm
w			21		g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

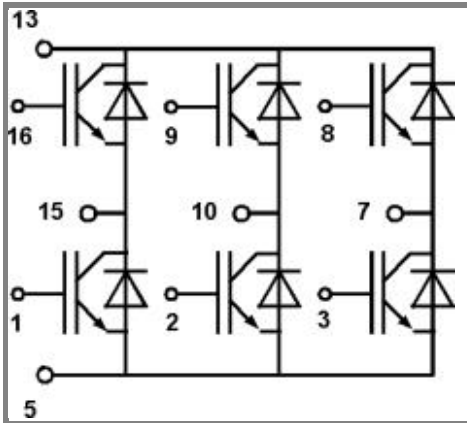
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.







Case T47 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T 47

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